

Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz



#### Features

Reference: 5V/60mA/2332.5 MHz

- Gain: 19.0 dB
- Eval Board NF: 0.36 dB
- 0P1dB: 21.0 dBm
- 0IP3: 36.0 dBm
- AEC-Q100 Grade 2 Qual Pending
- 100% Device Reflow at Assembly
- 100% Optical Die Inspection

**Product Description** 

GRF2071-W is a linear, ultra-low noise amplifier designed for automotive satellite radio multi-stage LNAs, signal booster and GPS applications.

With its ultra-low noise and high gain characteristics, this amplifier is an ideal first-stage LNA solution for high-performance, multi-stage SDARS LNA designs. With superior performance, it offers a drop-in alternative to legacy SDARS LNA solutions.

This device is part of a growing family of automotive-qualified ultra-low noise amplifiers targeted for stage 1 SDARS LNA and compensator applications to include:

GRF2071-W: 0.7 to 2.7 GHz

Preliminary

- GRF2072-W: 1.5 to 3.8 GHz
- GRF2073-W: 2.0 to 6.0 GHz

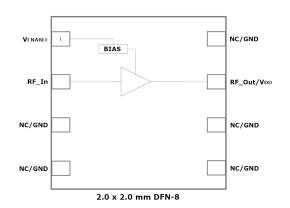
Each of the above devices offers ultra-low NF with different gain levels for optimal performance within a variety of radio architectures.

Please consult with the GRF applications engineering team for application notes and custom tuning/evaluation board data. De-embedded s-parameters with NF data are available on the website.

- Flexible Bias Voltage and Current
- Process: GaAs pHEMT

#### **Applications**

- SDARS LNA
- Cellular Boosters (Compensator)
- High-performance GPS





Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

## **Absolute Ratings:**

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	Vdd	0	6.0	V
RF Input Power: (Load VSWR < 2:1; V <sub>D</sub> : 5.0 volts)	P <sub>IN MAX</sub>		23	dBm
Operating Temperature (Package Heat Sink)	Т <sub>АМВ</sub>	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P <sub>DISS MAX</sub>		500	mW
Electrostatic Discharge:				
Charged Device Model:	CDM	1500		V
Human Body Model:	HBM	500		V
Storage:				
Storage Temperature	Tstg	-65	150	°C
Moisture Sensitivity Level	MSL		1	-

Preliminary



Caution! ESD Sensitive Device

Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2071-W landing page: Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

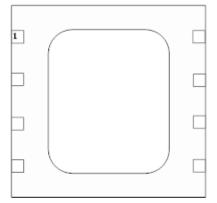
### Link to manufacturing note





Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

### Pin Out (Top View)



### **Pin Assignments:**

Pin	Name	Description	Note
1	VENABLE	Enable Voltage Input	VENABLE and series resistor set IDDQ. VENABLE < =0.2 volts disables device. On -die pull-down resistor will turn the part off if this node is allowed to float.
2	RF_In	RF Input	External match must provide DC block
3	NC/GND	No Connect or Ground	No internal connection to die
4	NC/GND	No Connect or Ground	No internal connection to die
5	NC/GND	No Connect or Ground	No internal connection to die
6	NC/GND	No Connect or Ground	No internal connection to die
7	RF_Out/VDD	RF Output	Provide device VDD via external bias inductor
8	NC/GND	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recom- mend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.





Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

### **Nominal Operating Parameters:**

Parameter	Symbol	Specification			Unit	Condition	
Farameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Gain Mode (Venable high)						V <sub>DD</sub> = 5.0 V, T <sub>A</sub> = 25 °C	
Test Frequency	FTEST		2332.5		MHz	1.7 to 2.7 GHz Tune	
Evaluation Board Gain	S21	15.5	17.0	18.5	dB		
Evaluation Board Noise Figure	NF		0.45	0.65	dB	Evaluation Board SMA to SMA	
Output 3rd Order Intercept Point	OIP3		36.5		dBm	4.0 dBm $P_{\text{OUT}}$ per tone at 2 MHz Spacing (2331.5 and 2333.5 MHz)	
Output 1dB Compression Point	OP1dB	19.0	21.0		dBm		
Switching Rise Time	T <sub>RISE</sub>		700		ns		
Switching Fall Time	T <sub>FALL</sub>		300		ns		
Supply Current	ldd		60		mA		
Enable Current	IENABLE		3.0		mA		
Thermal Data							
Thermal Resistance (measured via IR scan)	Θјс		60		°C/W	On standard evaluation board	
Channel Temperature @ +85 C Reference (Package Heat Sink)	Tchannel		103 (see note)		٥C	Vdd: 5.0 V; Iddq: 60 mA; No RF; Pdiss: 300 mW	

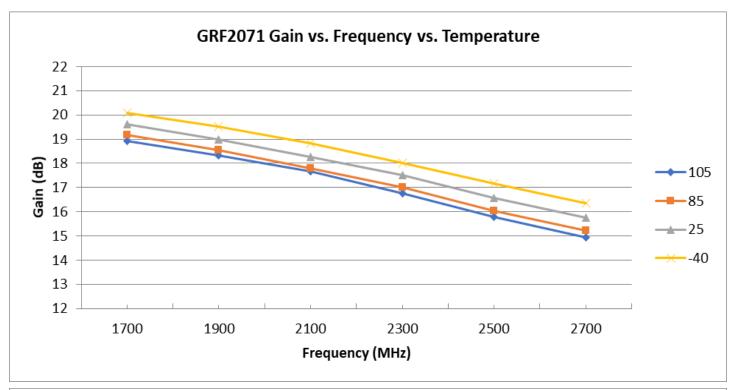
Note: MTTF >10^6 hours for TCHANNEL < =170 degrees C.

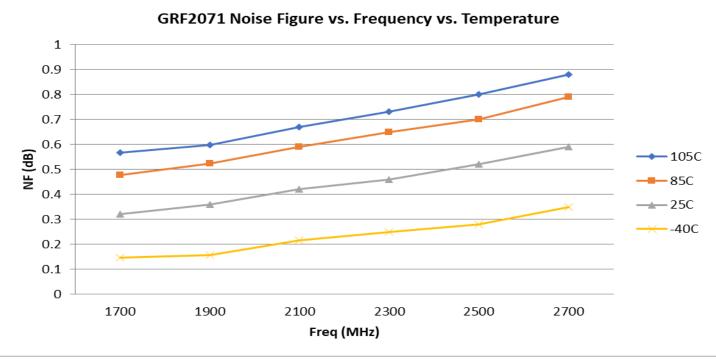




Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

**GRF2071-W Evaluation Board Measured Data:** 



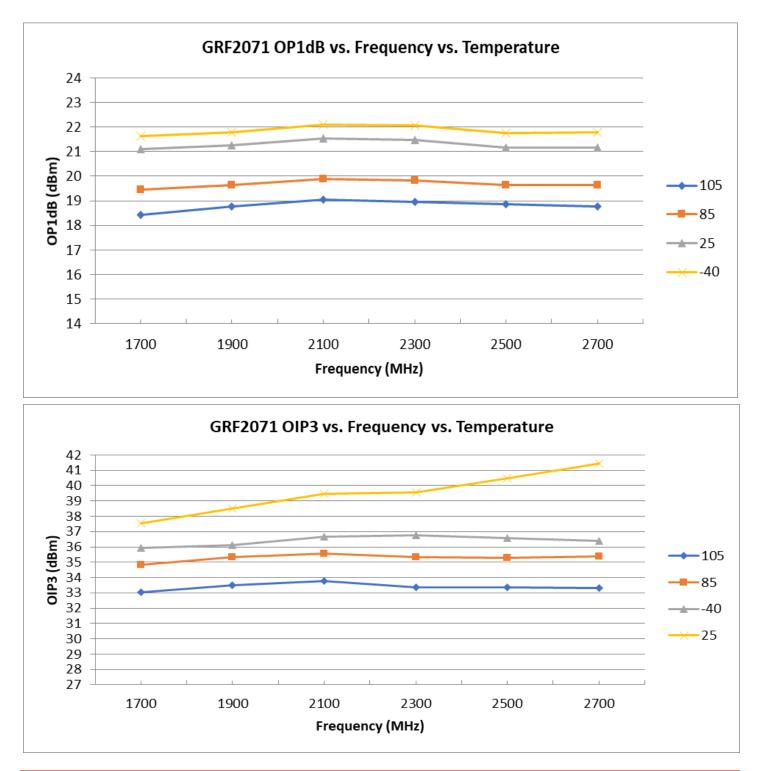






Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

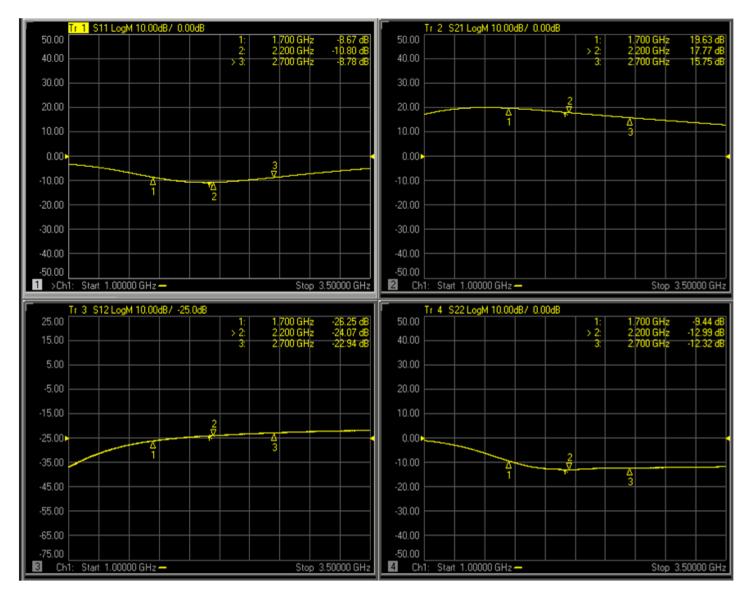
**GRF2071-W Evaluation Board Measured Data:** 





Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

### GRF2071-W Evaluation Board S-Pars: (1.7 to 2.7 GHz Match)

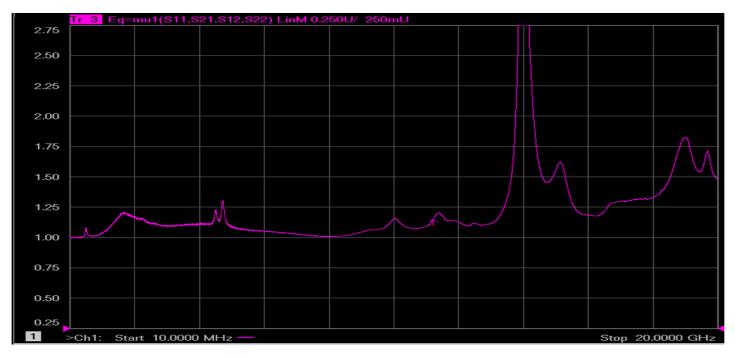


Preliminary

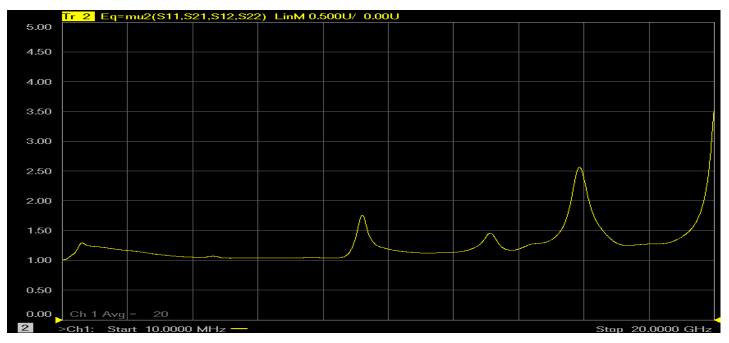


Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

GRF2071-W Evaluation Board Stability Mu/Mu Prime Factors: (1.7 to 2.7 GHz Match)



Note: Mu >= 1.0 implies unconditional stability.



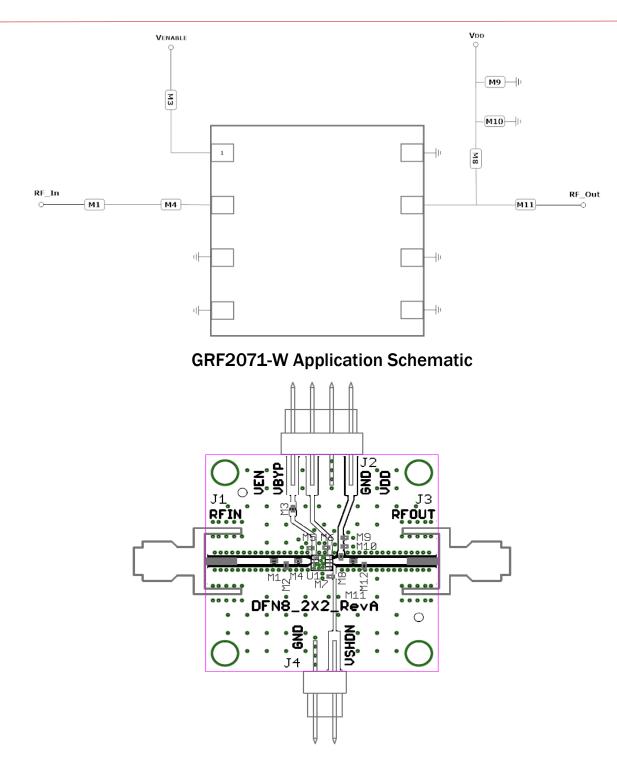
Note: Mu Prime >= 1.0 implies unconditional stability.



 $\Lambda$  pp

## GRF2071-W

Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz



**GRF2071-W EVB Assembly Drawing** 

Guerrilla RF Proprietary Information. Guerrilla RFTM and the composite logo of Guerrilla RFTM are trademarks of Guerrilla RF, Inc. @2014 Guerrilla RF, Inc. All rights reserved.



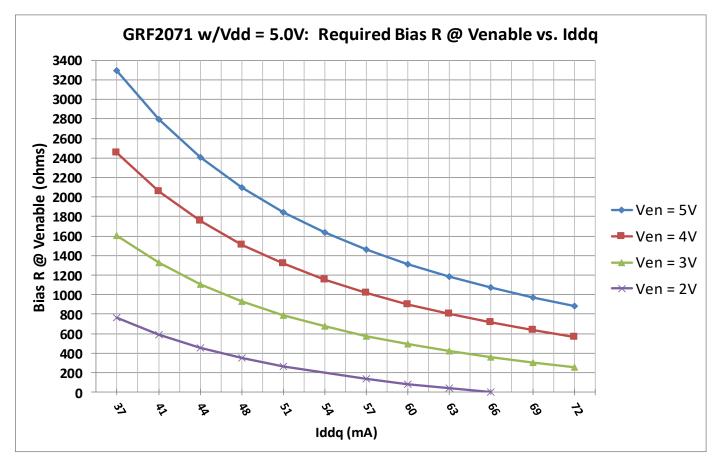


Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1	Capacitor	Murata	GJM	12 pF	0402	ok
M3	Resistor	Various	5%	Sets Iddq	0402	ok
M4	Inductor	Coilcraft	HP	2.0 nH	0402	ok
M8	Inductor	Murata	LQG	3.3 nH	0402	ok
M9	Capacitor	Murata	GRM	0.1 uF	0402	ok
M10	Capacitor	Murata	GRM	100 pF	0402	ok
M11	Capacitor	Murata	GJM	2.7 pF	0402	ok
Evaluation Board	DFN8_2x2_RevA	_	_	_	_	-

#### GRF2071-W Standard Evaluation Board BOM: (1.7 to 2.7 GHz Tune)

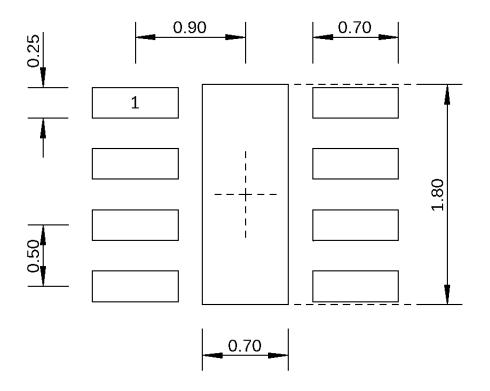
#### **GRF2071-W Bias Resistor Selection Curves:**







Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

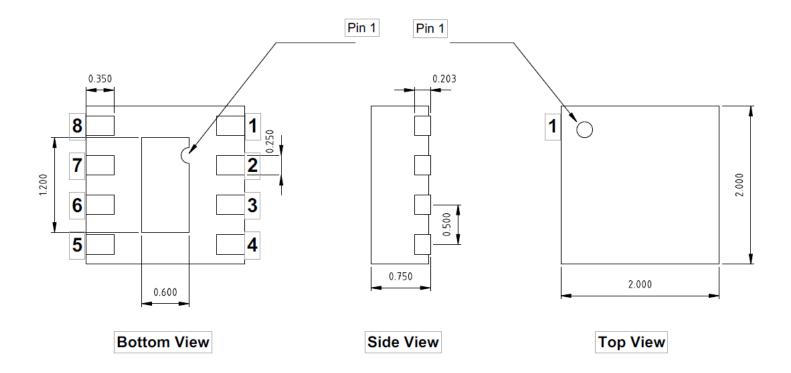


**Dimensions in millimeters** 

2.0 mm DFN-8 Suggested PCB Footprint (Top View)



Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz



2.0 x 2.0 DFN-8 Package Dimensions (mm)



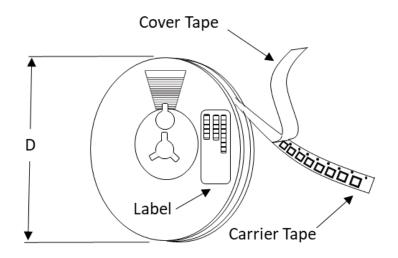
## GRF2071-W

Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

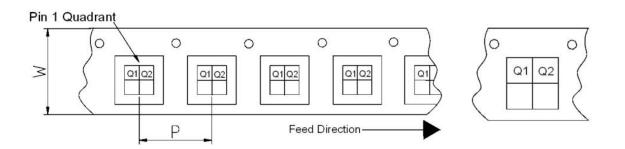
#### Tape and Reel Information:

Guerrilla RF's Tape and Reel specification complies with the Electronics Industries Association (EIA) standards for 'Embossed Carrier Tape of Surface Mount Components for Automatic Handling". Reference EIA-481. See the table on the following page for Tape and Reel specifications along with units per reel.

Devices are loaded with pins down into the carrier pocket with protective cover tape, wound into a plastic reel. Each reel will be packaged in a cardboard box. There will be product labels on the reel, the protective ESD bag and the outside surface of the box.



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information







Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

#### Tape and Reel Specification and Device Package Information Table

Package			Carrier Tape			Reel		
Туре	Dimensions (mm)	Leads	Weight (mg)	Width (W) (mm)	Pocket Pitch (P) (mm)	Pin 1 Quad- rant	Diameter (D) (inches)	Units per Reel
QFN	2.0 x 2.0 x 0.50	12	7	8	4	Q1	7	2500
QFN	3.0 x 3.0 x 0.85	16	24	12	8	Q1	7	1500
DFN	1.5 x 1.5 x 0.45	6	4	8	4	Q1	7	2500
DFN	2.0 x 2.0 x 0.75	8	12	8	4	Q1	7	2500
LFM	3.5 x 3.5 x 0.75	See note	TBD	12	8	Q2	7	1500
LFM	4.0 x 4.0 x 0.75	See note	TBD	12	8	Q2	7	1500

Note: Lead count may vary. Reference applicable product data sheet



# GRF2071-W

### Ultra-Low Noise Amplifier Tuning Range: 0.7 to 2.7 GHz

Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on de- vice size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

This datasheet, including the information contained in it, is provided by Guerrilla RF as a service to its customers and may be used for informational purposes only by the customer. Guerrilla RF assumes no responsibility for errors or omissions on this datasheet or the information contained herein. Information provided is believed to be accurate and reliable, however, no responsibility is assumed by Guerrilla RF for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. Guerrilla RF assumes no liability for any datasheet, datasheet information, materials, products, product information, or other information provided hereunder, including the sale, distribution, reproduction or use of Guerrilla RF products, information or materials.

No license, whether express, implied, by estoppel, by implication or otherwise is granted by this datasheet for any intellectual property of Guerrilla RF, or any third party, including without limitation, patents, patent rights, copyrights, trademarks and trade secrets. All rights are reserved by Guerrilla RF.

All information herein, products, product information, datasheets, and datasheet information are subject to change and availability without notice. Guerrilla RF reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice. Guerrilla RF may further change its datasheet, product information, documentation, products, services, specifications or product descriptions at any time, without notice. Guerrilla RF makes no commitment to update any materials or information and shall have no responsibility whatsoever for conflicts, incompatibilities, or other difficulties arising from any future changes.

GUERRILLA RF INFORMATION, PRODUCTS, PRODUCT INFORMATION, DATASHEETS AND DATASHEET INFORMATION ARE PROVIDED "AS IS" AND WITHOUT WAR-RANTY OF ANY KIND, WHETHER EXPRESS, IMPLIED, STATUTORY, OR OTHERWISE, INCLUDING FITNESS FOR A PARTICULAR PURPOSE OR USE, MERCHANTABILITY, PERFORMANCE, QUALITY OR NON-INFRINGEMENT OF ANY INTELLECTUAL PROPERTY RIGHT; ALL SUCH WARRANTIES ARE HEREBY EXPRESSLY DISCLAIMED. GUER-RILLA RF DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATE-RIALS. GUERRILLA RF SHALL NOT BE LIABLE FOR ANY DAMAGES, INCLUDING BUT NOT LIMITED TO ANY SPECIAL, INDIRECT, INCIDENTAL, STATUTORY, OR CONSE-QUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS THAT MAY RESULT FROM THE USE OF THE MATERIALS OR INFOR-MATION, WHETHER OR NOT THE RECIPIENT OF MATERIALS HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGE.

Customers are solely responsible for their use of Guerrilla RF products in the Customer's products and applications or in ways which deviate from Guerrilla RF's published specifications, either intentionally or as a result of design defects, errors, or operation of products outside of published parameters or design specifications. Customers should include design and operating safeguards to minimize these and other risks. Guerrilla RF assumes no liability or responsibility for applications assistance, customer product design, or damage to any equipment resulting from the use of Guerrilla RF products outside of stated published specifications or parameters.

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Guerrilla RF: